

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IXTY5N50P

### • FEATURES

- Static drain-source on-resistance:  $R_{DS}(on) \le 1.4\Omega@V_{GS}=10V$
- · Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATION

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

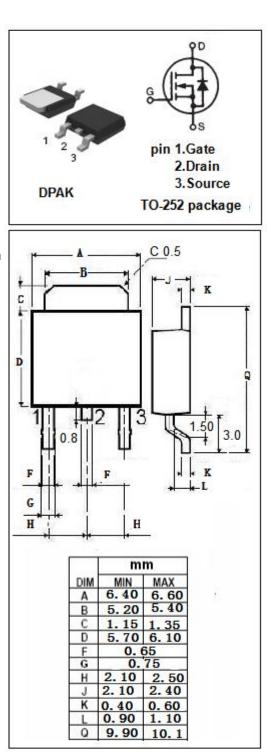
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	500	V
V <sub>GS</sub>	Gate-Source Voltage	±30	V
ID	Drain Current-Continuous	4.8	А
IDM	Drain Current-Single Pulsed	10	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	al Dissipation @Tc=25°C 89	
Tj	Operating Junction Temperature	-55~150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	1.40	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	500		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 50 μ A	3.0	5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 2.4A		1.4	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 125°C		50	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 4.8A; V <sub>GS</sub> = 0V		1.5	V

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